

HD26LS32A

Quadruple Differential Line Receivers With 3 State Outputs

REJ03D0296-0200Z (Previous ADE-205-578 (Z)) Rev.2.00 Jul.16.2004

Description

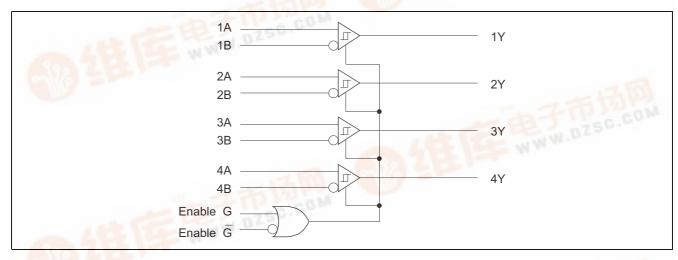
The HD26LS32A features quadruple line receivers designed to meet the specs of EIA standard RS-422A and RS-423. This device operates from a single 5 V power supply. The enable function is common to all four receivers and offers a choice of active high or active low input. Fail safe design ensures that if the inputs are open, the outputs will always be high.

Features

Ordering Information

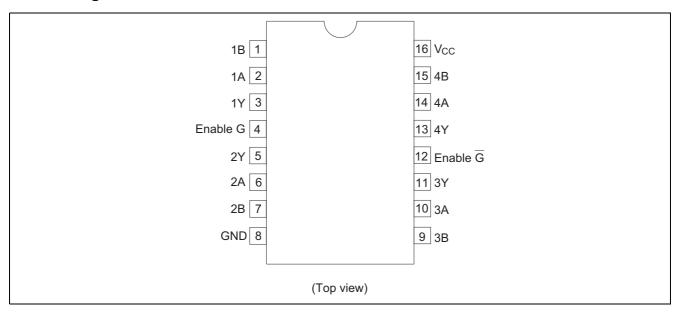
Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD26LS32AP	DILP-16 pin (JEITA)	DP-16E, -16FV	P	W.DZSU.

Logic Diagram





Pin Arrangement



Function Table

Differential Input	Enable	Output	
A – B	G	G	Y
V _{ID} ≥ V _{TH}	Н	Х	Н
	X	L	Н
$V_{TL} < V_{ID} < V_{TH}$	Н	Х	?
	X	L	?
V _{ID} ≤ V _{TL}	Н	Х	L
	x	L	L
Χ	L	Н	Z

H : High level
L : Low level
X : Immaterial
? : Irrelevant
Z : High impedance

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply Voltage	V _{CC} *1	7.0	V
Input Voltage A or B	V _{IN}	±25	V
Differential Input Voltage	V _{ID} * ²	±25	V
Enable Input Voltage	V _{IN}	7	V
Output Sink Current	lout	50	mA
Continuous Total Dissipation	P _T	1	W
Operating Temperature	Topr	0 to +70	°C
Storage Temperature	Tstg	-65 to 150	°C

Notes: 1. All voltage values except for differential input voltage are with respect to network ground terminal.

- 2. Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.
- 3. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Min	Тур	Max	Unit
Supply Voltage	V _{CC}	4.75	5.00	5.25	V
In Phase Input Voltage	V _{IC}	_		±7.0	V
Output Current	I _{OH}			-440	μΑ
	I _{OL}	_		8	mA
Operating Temperature	Topr	0		70	°C

Electrical Characteristics (Ta = 0 to +70°C)

Item	Symbol	Min	Typ*1	Max	Unit	Conditions	
Differential Input High	V_{TH}	_	_	0.2	V	$V_{IC} = -7 \text{ to } +7 \text{ V}$	$V_{OH} = 2.7V$, $I_{OH} = -440 \mu A$
Threshold Voltage							
Differential Input Low	V_{TL}	_	_	-0.2			$V_{OL} = 0.4 \text{ V}, I_{OL} = 4 \text{ mA}$
Threshold Voltage		_	_	-0.2			$V_{OL} = 0.45 \text{ V}, I_{OL} = 8 \text{ mA}$
Input Hysteresis*2	$V_{TH} - V_{TL}$	_	50	_	mV		
Enable Input Voltage	V_{IH}	2.0	_	_	V		
	V_{IL}	_	_	8.0			
Enable Input Clamp	V_{IK}		_	-1.5		$V_{CC} = 4.75 \text{ V}, I_{IN} =$	= –18 mA
Voltage	\/	2.7				\/ - 4.75.\/	V = 1 V I = 440 ·· A
Output Voltage	V _{OH}	2.1	_	_			$V_{ID} = 1 \text{ V}, I_{OH} = -440 \mu\text{A}$
	V_{OL}		_	0.4		$V_{\rm L}$ (G) = 0.8 V	$V_{ID} = -1 \text{ V, } I_{OL} = 4 \text{ mA}$
		_	_	0.45			$V_{ID} = -1 \text{ V}, I_{OL} = 8 \text{ mA}$
Off State (High	I_{OZ}	_	_	20	μΑ	V _{CC} = 5.25 V	V _O = 2.4 V
Impedance) Output Current		_	_	-20			V _O = 0.4 V
Line Input Current	II	_	_	1.2	mΑ	$V_1 = 15 \text{ V}$, Other	Inputs –10 to +15 V
		_	_	-1.7		$V_I = -15 \text{ V}$, Other	r Inputs –15 to +10 V
Enable Input Current	I _I (EN)	_	_	100	μΑ	V _I = 5.5 V	
	I _{IH}		_	20		V _I = 2.7 V	
	I _{IL}	_	_	-0.36	mΑ	V _I = 0.4 V	
Input Resistance	ri	12	15	_	kΩ	$V_{IC} = -15 \text{ to } +15$	V (Other Inputs AC GND)
Short Circuit Output Current	l _{os} *3	–15	_	-85	mA	V _{CC} = 5.25 V	
Supply Current	I _{cc}		52	70		$V_{CC} = 5.25 \text{ V}, V_{I} =$	= 0 V (All Outputs Disable)

Notes: 1. All typical values are at V_{CC} = 5 V, Ta = 25°C, V_{IC} = 0.

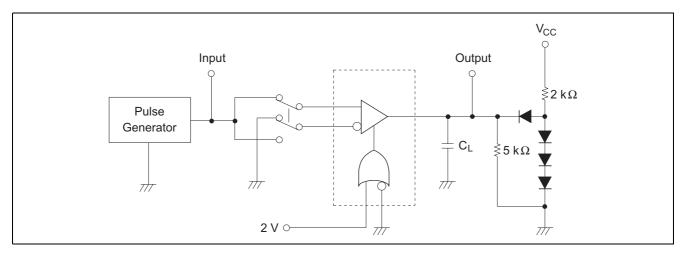
- 2. Hysteresis is the differential between the positive going input threshold voltage and the negative going input threshold voltage.
- 3. Not more than one output should be shorted at a time.

Switching Characteristics ($V_{CC} = 5 \text{ V}$, Ta = 25°C)

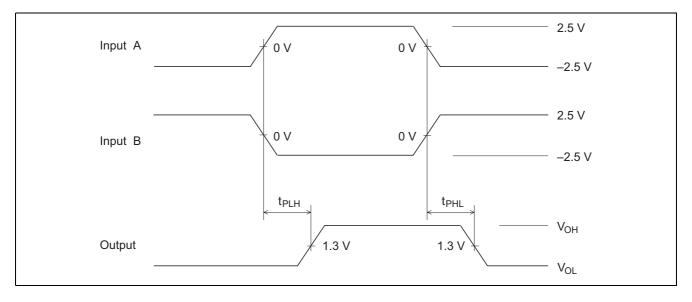
Item	Symbol	Min	Тур	Max	Unit	Conditions
Propagation Delay Time	t _{PLH}	_	20	35	ns	C _L = 15 pF
	t _{PHL}	_	22	35		
Output Enable Time	t _{zH}	_	17	22	ns	C _L = 15 pF
	t_{zL}	_	20	25		
Output Disable Time	t _{HZ}	_	21	30	ns	C _L = 5 pF
	t _{LZ}	_	30	40		

1. t_{PLH} , t_{PHL}

Test circuit

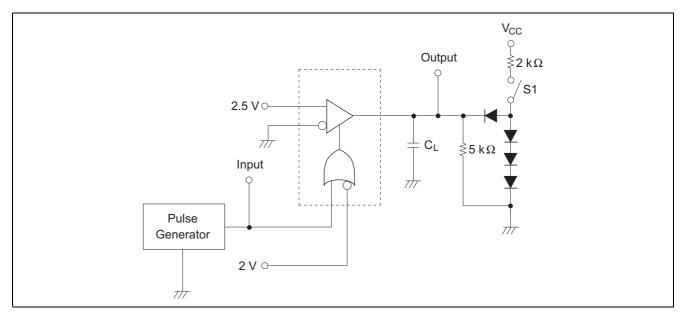


Waveforms

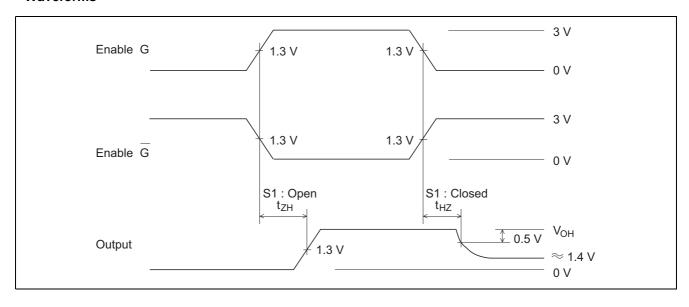


$2. \quad t_{HZ}, \, t_{ZH}$

Test circuit

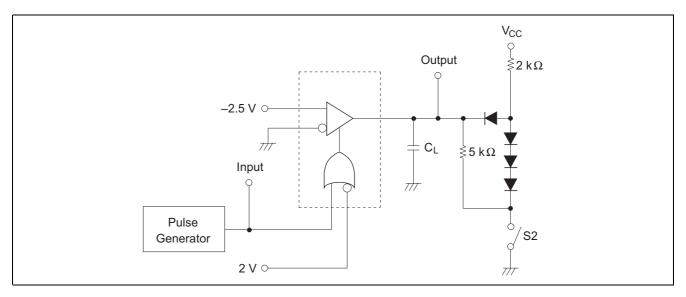


Waveforms

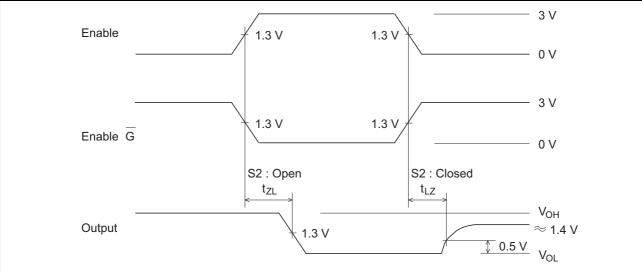


3. t_{LZ} , t_{ZL}

Test circuit



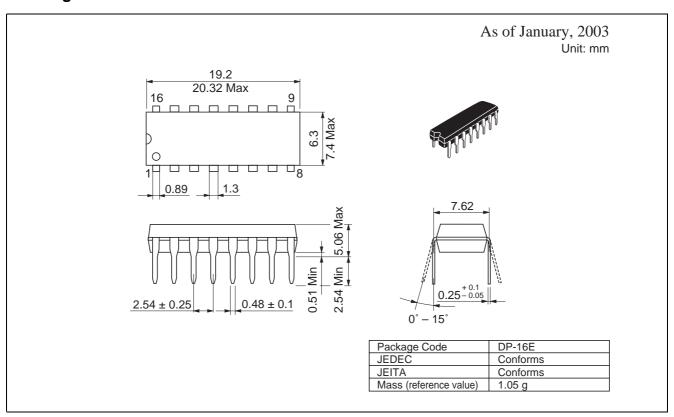
Waveforms

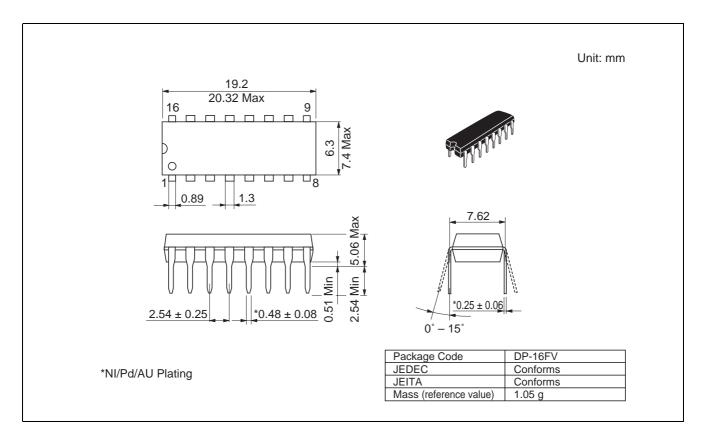


Notes:

- 1. The pulse generator has the following characteristics: PRR = 1 MHz, 50% duty cycle, $t_i \le 6$ ns, $t_i \le 6$ ns, Zout = 50 Ω .
- 2. C_L includes probe and jig capacitance.
- 3. All diodes are 1S2074(H).
- 4. To test G input, ground G input and apply an inverted input waveform.

Package Dimensions





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